NSN 5961-01-159-2481

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-159-2481 **Inclosure Material:** Glass **Overall Length:** 0.265 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.124 inches **Function For Which Designed:** Voltage variable capacitor Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-14 **Mounting Method: Terminal Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 37.0 breakdown voltage, dc **Current Rating Per Characteristic:** 3.00 microamperes forward current, average peak **Capacitance Rating In Picofarads:** 100.0 **Test Data Document:** 28815-68-108294 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**